

CMOS Digital Integrated Circuits Silicon Monolithic

# 74HCT4051D,74HCT4052D

#### 1. Functional Description

74HCT4051D:8-Channel Analog Multiplexer/Demultiplexer 74HCT4052D:Dual 4-Channel Analog Multiplexer/Demultiplexer

#### 2. General

The 74HCT4051D/74HCT4052D are high speed CMOS ANALOG MULTIPLEXER/DEMULTIPLEXER fabricated with silicon gate C $^2$ MOS technology. They achieve the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

This device may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. This inputs are compatible with TTL, NMOS and CMOS output voltage levels.

The 74HCT4051D has an 8 channel configuration and the 74HCT4052D has a 4 channel  $\times$  2 configuration.

The digital signal to the control terminal turns "ON" the corresponding switch of each channel a large amplitude signal ( $V_{CC}$  -  $V_{EE}$ ) can then be switched by the small logical amplitude ( $V_{CC}$  - GND) control signal.

For example, in the case of  $V_{\rm CC}$  = 5 V, GND = 0 V,  $V_{\rm EE}$  = -5 V, signals between -5 V and +5 V can be switched from the logical circuit with a single power supply of 5 V. As the ON-resistance of each switch is low, they can be connected to circuits with low input impedance.

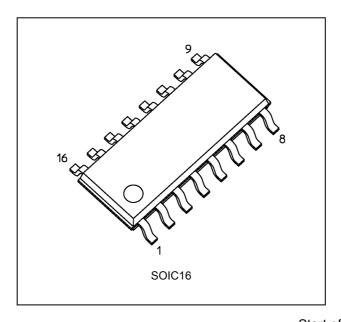
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

#### 3. Features

- (1) Wide operating temperature range:  $T_{\rm opr} = \text{-}40$  to 125 °C (Note 1)
- (2) Low power dissipation:  $I_{CC} = 4.0 \mu A \text{ (max)} \text{ (V}_{CC} = 5.5 \text{ V}, V_{EE} = \text{GND}, T_a = 25 \text{ °C)}$
- (3) Compatible with TTL output:  $V_{IH} = 2.0 \text{ V (min)}$ ,  $V_{IL} = 0.8 \text{ V (max)}$
- (4) Wide interfacing ability: LSTTL, NMOS, CMOS
- (5) Low ON-resistance:  $R_{ON} = 50 \Omega$  (typ.) at  $V_{CC} V_{EE} = 9 V$
- (6) High degree of linearity: THD = 0.020 % (typ.) at  $V_{CC} V_{EE} = 9 \text{ V}$

Note 1: Operating Range spec of  $T_{opr}$  = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.

#### 4. Packaging



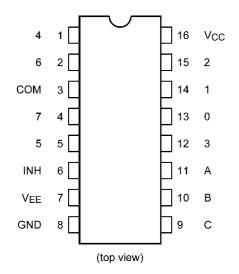
Start of commercial production

2020-07

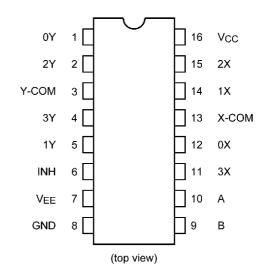


#### 5. Pin Assignment



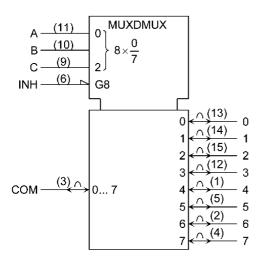


#### 74HCT4052D

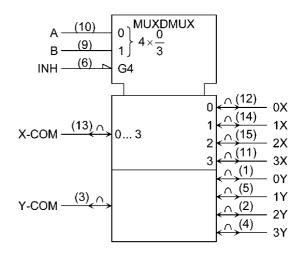


#### 6. IEC Logic Symbol

74HCT4051D

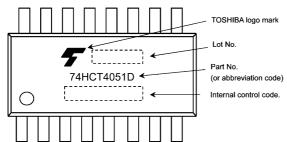


#### 74HCT4052D

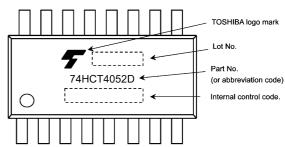


#### 7. Marking





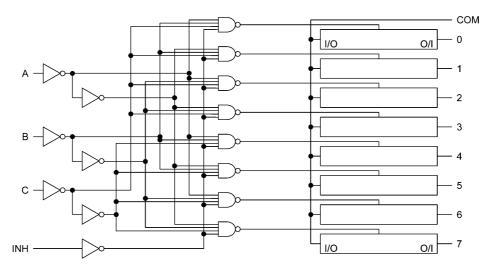
#### 74HCT4052D



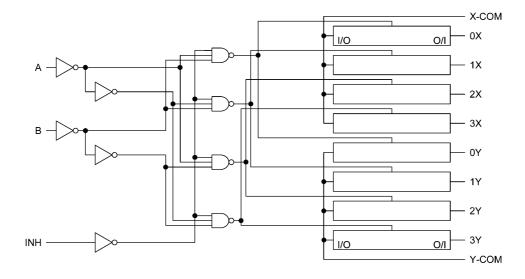


# 8. System Diagram

74HCT4051D



#### 74HCT4052D





#### 9. Truth Table

| Input<br>Inhibit | Input<br>C* | Input<br>B | Input<br>A | ON Channel<br>74HCT4051D | ON Channel<br>74HCT4052D |
|------------------|-------------|------------|------------|--------------------------|--------------------------|
| L                | L           | L          | L          | 0                        | 0X, 0Y                   |
| L                | L           | L          | Н          | 1                        | 1X, 1Y                   |
| L                | L           | Н          | L          | 2                        | 2X, 2Y                   |
| L                | L           | Н          | Н          | 3                        | 3X, 3Y                   |
| L                | Н           | L          | L          | 4                        | _                        |
| L                | Н           | L          | Н          | 5                        | _                        |
| L                | Н           | Н          | L          | 6                        | _                        |
| L                | Н           | Н          | Н          | 7                        | _                        |
| Н                | Х           | Х          | Х          | None                     | None                     |

X: Don't care

\*: Except 74HCT4052D

#### 10. Absolute Maximum Ratings (Note)

| Characteristics                 | Symbol                           | Note     | Rating                                         | Unit |
|---------------------------------|----------------------------------|----------|------------------------------------------------|------|
| Supply voltage                  | V <sub>CC</sub>                  |          | -0.5 to 7.0                                    | V    |
| Supply voltage                  | V <sub>EE</sub>                  |          | -7.0 to 0                                      | V    |
| Supply voltage                  | V <sub>CC</sub> -V <sub>EE</sub> |          | -0.5 to 13.0                                   | V    |
| Input voltage                   | V <sub>IN</sub>                  |          | -0.5 to V <sub>CC</sub> + 0.5                  | V    |
| Switch I/O voltage              | V <sub>I/O</sub>                 |          | V <sub>EE</sub> - 0.5 to V <sub>CC</sub> + 0.5 | V    |
| Input diode current             | I <sub>IK</sub>                  |          | ±20                                            | mA   |
| I/O diode current               | I <sub>I/OK</sub>                |          | ±20                                            | mA   |
| Switch through current          | I <sub>T</sub>                   |          | ±25                                            | mA   |
| V <sub>CC</sub> /ground current | I <sub>CC</sub>                  |          | ±50                                            | mA   |
| Power dissipation               | P <sub>D</sub>                   | (Note 1) | 500                                            | mW   |
| Storage temperature             | T <sub>stg</sub>                 |          | -65 to 150                                     | °C   |

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: P<sub>D</sub> derates linearly with -8 mW/°C above 85 °C.

#### 11. Operating Ranges (Note)

| Characteristics           | Symbol              | Note     | Rating                             | Unit |
|---------------------------|---------------------|----------|------------------------------------|------|
| Supply voltage            | V <sub>CC</sub>     |          | 4.5 to 5.5                         | V    |
| Supply voltage            | $V_{EE}$            |          | -6.0 to 0                          | V    |
| Supply voltage            | $V_{CC}$ - $V_{EE}$ |          | 4.5 to 11.0                        | V    |
| Input voltage             | V <sub>IN</sub>     |          | 0 to V <sub>CC</sub>               | V    |
| Switch I/O voltage        | V <sub>I/O</sub>    |          | V <sub>EE</sub> to V <sub>CC</sub> | V    |
| Operating temperature     | T <sub>opr</sub>    | (Note 1) | -40 to 125                         | °C   |
| Input rise and fall times | $t_r, t_f$          |          | 0 to 50                            | μS   |

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either V<sub>CC</sub> or GND.

Note 1: Operating Range spec of  $T_{opr}$  = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.



#### 12. Electrical Characteristics

# 12.1. DC Characteristics (Unless otherwise specified, $T_a = 25$ °C)

| Characteristics               | Symbol           | Test Condition                                                                                              | V <sub>EE</sub> (V) | V <sub>CC</sub> (V) | Min | Тур. | Max   | Unit |
|-------------------------------|------------------|-------------------------------------------------------------------------------------------------------------|---------------------|---------------------|-----|------|-------|------|
| High-level input voltage      | V <sub>IH</sub>  | _                                                                                                           |                     | 4.5 to 5.5          | 2.0 | _    | _     | V    |
| Low-level input voltage       | V <sub>IL</sub>  | _                                                                                                           |                     | 4.5 to 5.5          |     | _    | 0.8   | V    |
| ON-resistance                 | R <sub>ON</sub>  | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                                        | GND                 | 4.5                 | _   | 180  | 240   | Ω    |
|                               |                  | $ V_{I/O} = V_{CC}$ to $V_{EE}$<br>$ I_{I/O} \le 2 \text{ mA}$                                              | -4.5                | 4.5                 | _   | 140  | 190   |      |
|                               |                  |                                                                                                             | -5.5                | 5.5                 | _   | 135  | 180   |      |
|                               |                  | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                                        | GND                 | 4.5                 | _   | 150  | 200   |      |
|                               |                  | $V_{I/O} = V_{EE}$                                                                                          | -4.5                | 4.5                 | _   | 135  | 170   |      |
|                               |                  | I <sub>I/O</sub> ≤ 2 mA                                                                                     | -5.5                | 5.5                 |     | 125  | 170   |      |
|                               |                  | $V_{IN} = V_{IH}$ or $V_{IL}$                                                                               | GND                 | 4.5                 |     | 95   | 130   |      |
|                               |                  | $V_{I/O} = V_{CC}$                                                                                          | -4.5                | 4.5                 |     | 75   | 100   |      |
|                               |                  | $I_{I/O} \le 2 \text{ mA}$                                                                                  | -5.5                | 5.5                 | _   | 70   | 100   |      |
| Difference of ON-resistance   | $\Delta R_{ON}$  | $V_{IN} = V_{IH} \text{ or } V_{IL}$<br>$V_{I/O} = V_{CC} \text{ to } V_{EE}$<br>$I_{I/O} \le 2 \text{ mA}$ | GND                 | 4.5                 | _   | 10   | 30    | Ω    |
| between switches              |                  |                                                                                                             | -4.5                | 4.5                 |     | 5    | 12    |      |
|                               |                  |                                                                                                             | -5.5                | 5.5                 |     | 5    | 11    |      |
| Input/Output leakage current  | I <sub>OFF</sub> | $V_{OS} = V_{CC}$ or GND                                                                                    | GND                 | 5.5                 |     | _    | ±0.06 | μА   |
| (Switch OFF)                  |                  | $V_{IS}$ = GND or $V_{CC}$<br>$V_{IN}$ = $V_{IH}$ or $V_{IL}$                                               | -5.5                | 5.5                 | _   | _    | ±0.1  |      |
| Input/Output leakage current  | I <sub>I/O</sub> | V <sub>OS</sub> = V <sub>CC</sub> or GND                                                                    | GND                 | 5.5                 | _   | _    | ±0.06 | μА   |
| (Switch ON)                   |                  | $V_{IN} = V_{IH}$ or $V_{IL}$                                                                               | -5.5                | 5.5                 | _   | _    | ±0.1  |      |
| Control input leakage current | I <sub>IN</sub>  | V <sub>IN</sub> = V <sub>CC</sub> or GND                                                                    | GND                 | 5.5                 |     | _    | ±0.1  | μΑ   |
| Quiescent supply current      | I <sub>CC</sub>  | V <sub>IN</sub> = V <sub>CC</sub> or GND                                                                    | GND                 | 5.5                 | -   | _    | 4.0   | μА   |
|                               |                  |                                                                                                             | -5.5                | 5.5                 | -   | _    | 8.0   |      |
|                               |                  | Per input:<br>$V_{IN}$ = 0.5 V or 2.4 V<br>Other input: $V_{CC}$ or GND                                     | GND                 | 5.5                 | _   | _    | 2.0   | mA   |



# 12.2. DC Characteristics (Unless otherwise specified, $T_a$ = -40 to 85 °C)

| Characteristics                           | Symbol           | Test Condition                                                                           | V <sub>EE</sub> (V) | V <sub>CC</sub> (V) | Min | Max  | Unit |
|-------------------------------------------|------------------|------------------------------------------------------------------------------------------|---------------------|---------------------|-----|------|------|
| High-level input voltage                  | V <sub>IH</sub>  | _                                                                                        |                     | 4.5 to 5.5          | 2.0 | _    | V    |
| Low-level input voltage                   | V <sub>IL</sub>  | _                                                                                        |                     | 4.5 to 5.5          | _   | 0.8  | V    |
| ON-resistance                             | R <sub>ON</sub>  | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                     | GND                 | 4.5                 | _   | 300  | Ω    |
|                                           |                  | $V_{I/O} = V_{CC}$ to $V_{EE}$<br>$I_{I/O} \le 2 \text{ mA}$                             | -4.5                | 4.5                 | _   | 240  | ]    |
|                                           |                  | 11/0 ≥ 2 111A                                                                            | -5.5                | 5.5                 | _   | 225  |      |
|                                           |                  | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                     | GND                 | 4.5                 | _   | 250  | ]    |
|                                           |                  | $V_{I/O} = V_{EE}$<br>$I_{I/O} \le 2 \text{ mA}$                                         | -4.5                | 4.5                 | _   | 215  | ]    |
|                                           |                  | 11/0 ≥ 2 111A                                                                            | -5.5                | 5.5                 | _   | 215  |      |
|                                           |                  | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                     | GND                 | 4.5                 | _   | 165  | ]    |
|                                           |                  | $V_{I/O} = V_{CC}$<br>$I_{I/O} \le 2 \text{ mA}$                                         | -4.5                | 4.5                 | _   | 125  |      |
|                                           |                  | 11/0 ≥ 2 111A                                                                            | -5.5                | 5.5                 | _   | 125  |      |
| Difference of ON-resistance               | $\Delta R_{ON}$  | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                     | GND                 | 4.5                 | _   | 35   | Ω    |
| between switches                          |                  | $V_{I/O} = V_{CC}$ to $V_{EE}$<br>$I_{I/O} \le 2 \text{ mA}$                             | -4.5                | 4.5                 | _   | 15   |      |
|                                           |                  | 11/0 = 2 111A                                                                            | -5.5                | 5.5                 | _   | 14   |      |
| Input/Output leakage current (Switch OFF) | I <sub>OFF</sub> | $V_{OS} = V_{CC}$ or GND<br>$V_{IS} = GND$ or $V_{CC}$                                   | GND                 | 5.5                 | _   | ±0.6 | μА   |
| (Switch Of 1)                             |                  | $V_{IN} = V_{IH}$ or $V_{IL}$                                                            | -5.5                | 5.5                 | _   | ±1.0 |      |
| Input/Output leakage current              | I <sub>I/O</sub> | V <sub>OS</sub> = V <sub>CC</sub> or GND                                                 | GND                 | 5.5                 | _   | ±0.6 | μА   |
| (Switch ON)                               |                  | $V_{IN} = V_{IH} \text{ or } V_{IL}$                                                     | -5.5                | 5.5                 | _   | ±1.0 | ]    |
| Control input leakage current             | I <sub>IN</sub>  | V <sub>IN</sub> = V <sub>CC</sub> or GND                                                 | GND                 | 5.5                 | _   | ±1.0 | μА   |
| Quiescent supply current                  | I <sub>CC</sub>  | V <sub>IN</sub> = V <sub>CC</sub> or GND                                                 | GND                 | 5.5                 | _   | 40.0 | μА   |
|                                           |                  | -5.5                                                                                     | -5.5                | 5.5                 | _   | 80.0 |      |
|                                           |                  | Per input:<br>$V_{IN} = 0.5 \text{ V or } 2.4 \text{ V}$<br>Other input: $V_{CC}$ or GND | GND                 | 5.5                 | _   | 2.9  | mA   |



# 12.3. DC Characteristics (Note) (Unless otherwise specified, $T_a$ = -40 to 125 °C)

| Characteristics               | Symbol           | Test Condition                                                                        | V <sub>EE</sub> (V) | V <sub>CC</sub> (V) | Min | Max   | Unit |
|-------------------------------|------------------|---------------------------------------------------------------------------------------|---------------------|---------------------|-----|-------|------|
| High-level input voltage      | V <sub>IH</sub>  | _                                                                                     |                     | 4.5 to 5.5          | 2.0 | _     | V    |
| Low-level input voltage       | V <sub>IL</sub>  | _                                                                                     |                     | 4.5 to 5.5          |     | 0.8   | V    |
| ON-resistance                 | R <sub>ON</sub>  | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                  | GND                 | 4.5                 | _   | 340   | Ω    |
|                               |                  | $V_{I/O} = V_{CC}$ to $V_{EE}$<br>$I_{I/O} \le 2 \text{ mA}$                          | -4.5                | 4.5                 | _   | 275   |      |
|                               |                  | 11/0 = 2 11/A                                                                         | -5.5                | 5.5                 |     | 255   |      |
|                               |                  | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                  | GND                 | 4.5                 | _   | 285   |      |
|                               |                  | $V_{I/O} = V_{EE}$<br>$I_{I/O} \le 2 \text{ mA}$                                      | -4.5                | 4.5                 | _   | 245   |      |
|                               |                  |                                                                                       | -5.5                | 5.5                 | _   | 245   |      |
|                               |                  | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                  | GND                 | 4.5                 | _   | 190   |      |
|                               |                  | $V_{I/O} = V_{CC}$ $I_{I/O} \le 2 \text{ mA}$                                         | -4.5                | 4.5                 | _   | 145   |      |
|                               |                  |                                                                                       | -5.5                | 5.5                 | _   | 145   |      |
| Difference of ON-resistance   | $\Delta R_{ON}$  | V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>                                  | GND                 | 4.5                 | _   | 35    | Ω    |
| between switches              |                  | $V_{I/O} = V_{CC}$ to $V_{EE}$<br>$I_{I/O} \le 2 \text{ mA}$                          | -4.5                | 4.5                 | _   | 15    |      |
|                               |                  |                                                                                       | -5.5                | 5.5                 | _   | 14    |      |
| Input/Output leakage current  | I <sub>OFF</sub> | $V_{OS} = V_{CC}$ or GND                                                              | GND                 | 5.5                 | _   | ±3.0  | μА   |
| (Switch OFF)                  |                  | $V_{IS}$ = GND or $V_{CC}$<br>$V_{IN}$ = $V_{IH}$ or $V_{IL}$                         | -5.5                | 5.5                 |     | ±5.0  |      |
| Input/Output leakage current  | I <sub>I/O</sub> | V <sub>OS</sub> = V <sub>CC</sub> or GND                                              | GND                 | 5.5                 |     | ±3.0  | μА   |
| (Switch ON)                   |                  | $V_{IN} = V_{IH} \text{ or } V_{IL}$                                                  | -5.5                | 5.5                 | _   | ±5.0  |      |
| Control input leakage current | I <sub>IN</sub>  | V <sub>IN</sub> = V <sub>CC</sub> or GND                                              | GND                 | 5.5                 | _   | ±1.0  | μА   |
| Quiescent supply current      | I <sub>CC</sub>  | V <sub>IN</sub> = V <sub>CC</sub> or GND                                              | GND                 | 5.5                 | _   | 80.0  | μА   |
|                               |                  |                                                                                       | -5.5                | 5.5                 | _   | 160.0 |      |
|                               |                  | Per input:<br>V <sub>IN</sub> = 0.5 V or 2.4 V<br>Other input: V <sub>CC</sub> or GND | GND                 | 5.5                 | _   | 2.9   | mA   |

Note: Operating Range spec of  $T_{opr}$  = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.



# 12.4. AC Characteristics (Unless otherwise specified, $C_L$ = 50 pF, $T_a$ = 25 °C, Input: $t_r$ = $t_f$ = 6 ns)

| Characteristics           | Part Number | Symbol             | Test Condition    | V <sub>EE</sub> (V) | V <sub>CC</sub> (V) | Min | Тур. | Max | Unit |
|---------------------------|-------------|--------------------|-------------------|---------------------|---------------------|-----|------|-----|------|
| Phase difference          |             | Ψι/Ο               | _                 | GND                 | 4.5                 | _   | 7    | 12  | ns   |
| between input to output   |             |                    |                   | GND                 | 5.5                 | _   | 6    | 10  |      |
|                           |             |                    |                   | -4.5                | 4.5                 | _   | 5    | _   |      |
| Output enable time        | 74HCT4051D  | $t_{PZL}, t_{PZH}$ | $R_L = 1 k\Omega$ | GND                 | 4.5                 |     | 30   | 45  | ns   |
|                           |             |                    | Figure 1          | GND                 | 5.5                 |     | 26   | 35  |      |
|                           |             |                    |                   | -4.5                | 4.5                 |     | 25   | 35  |      |
|                           | 74HCT4052D  |                    | $R_L = 1 k\Omega$ | GND                 | 4.5                 | _   | 30   | 45  | ns   |
|                           |             |                    | Figure 1          | GND                 | 5.5                 |     | 26   | 35  |      |
|                           |             |                    |                   | -4.5                | 4.5                 | _   | 25   | 35  |      |
| Output disable time       | 74HCT4051D  | $t_{PLZ},t_{PHZ}$  | $R_L = 1 k\Omega$ | GND                 | 4.5                 | _   | 22   | 30  | ns   |
|                           |             |                    | Figure 1          | GND                 | 5.5                 |     | 21   | 28  |      |
|                           |             |                    |                   | -4.5                | 4.5                 |     | 21   | 28  |      |
|                           | 74HCT4052D  |                    | $R_L = 1 k\Omega$ | GND                 | 4.5                 | _   | 22   | 30  | ns   |
|                           |             |                    | Figure 1          | GND                 | 5.5                 |     | 21   | 28  |      |
|                           |             |                    |                   | -4.5                | 4.5                 | _   | 21   | 28  |      |
| Control input capacitance |             | C <sub>IN</sub>    | _                 | _                   |                     | _   | 5    | 10  | pF   |
| Common terminal           | 74HCT4051D  | C <sub>IS</sub>    | Figure 2          | -5.0                | 5.0                 | _   | 36   | 70  | pF   |
| capacitance               | 74HCT4052D  |                    |                   |                     |                     | _   | 19   | 40  |      |
| Switch terminal           | 74HCT4051D  | Cos                | Figure 2          | -5.0                | 5.0                 | _   | 7    | 15  | pF   |
| capacitance               | 74HCT4052D  |                    |                   |                     |                     | _   | 7    | 15  |      |
| Feedthrough               | 74HCT4051D  | C <sub>IOS</sub>   | Figure 2          | -5.0                | 5.0                 |     | 0.75 | 2   | pF   |
| capacitance               | 74HCT4052D  |                    |                   |                     |                     | _   | 0.75 | 2   |      |
| Power dissipation         | 74HCT4051D  | C <sub>PD</sub>    | Figure 2          | GND                 | 5.0                 | _   | 11   | _   | pF   |
| capacitance               | 74HCT4052D  |                    | (Note 1)          |                     |                     |     | 19   |     |      |

Note 1:  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}$ 



# 12.5. AC Characteristics (Unless otherwise specified, $C_L$ = 50 pF, $T_a$ = -40 to 85 °C, Input: $t_r$ = $t_f$ = 6 ns)

| Characteristics             | Part Number | Symbol             | Test Condition    | V <sub>EE</sub> (V) | V <sub>CC</sub> (V) | Min | Max | Unit |
|-----------------------------|-------------|--------------------|-------------------|---------------------|---------------------|-----|-----|------|
| Phase difference between    |             | Ψι/Ο               | _                 | GND                 | 4.5                 | _   | 15  | ns   |
| input to output             |             |                    |                   | GND                 | 5.5                 |     | 13  |      |
|                             |             |                    |                   | -4.5                | 4.5                 |     |     |      |
| Output enable time          | 74HCT4051D  | $t_{PZL}, t_{PZH}$ | $R_L = 1 k\Omega$ | GND                 | 4.5                 | _   | 55  | ns   |
|                             |             |                    | Figure 1          | GND                 | 5.5                 | _   | 42  |      |
|                             |             |                    |                   | -4.5                | 4.5                 | _   | 41  |      |
|                             | 74HCT4052D  |                    | $R_L = 1 k\Omega$ | GND                 | 4.5                 | _   | 55  | ns   |
|                             |             |                    | Figure 1          | GND                 | 5.5                 |     | 42  |      |
|                             |             |                    |                   | -4.5                | 4.5                 |     | 41  |      |
| Output disable time         | 74HCT4051D  | $t_{PLZ}, t_{PHZ}$ | $R_L = 1 k\Omega$ | GND                 | 4.5                 | _   | 37  | ns   |
|                             |             |                    | Figure 1          | GND                 | 5.5                 |     | 34  |      |
|                             |             |                    |                   | -4.5                | 4.5                 |     | 34  |      |
|                             | 74HCT4052D  |                    | $R_L = 1 k\Omega$ | GND                 | 4.5                 | _   | 37  | ns   |
|                             |             |                    | Figure 1          | GND                 | 5.5                 |     | 34  |      |
|                             |             |                    |                   | -4.5                | 4.5                 |     | 34  |      |
| Control input capacitance   |             | C <sub>IN</sub>    | _                 | _                   |                     | _   | 10  | pF   |
| Common terminal             | 74HCT4051D  | C <sub>IS</sub>    | Figure 2          | -5.0                | 5.0                 |     | 70  | pF   |
| capacitance                 | 74HCT4052D  |                    |                   |                     |                     |     | 40  |      |
| Switch terminal capacitance | 74HCT4051D  | Cos                | Figure 2          | -5.0                | 5.0                 | _   | 15  | pF   |
|                             | 74HCT4052D  |                    |                   |                     |                     |     | 15  |      |
| Feedthrough capacitance     | 74HCT4051D  | C <sub>IOS</sub>   | Figure 2          | -5.0                | 5.0                 | _   | 2   | pF   |
|                             | 74HCT4052D  |                    |                   |                     |                     | _   | 2   |      |



12.6. AC Characteristics (Note) (Unless otherwise specified, CL = 50 pF,  $T_a$  = -40 to 125 °C, Input:  $t_r$  =  $t_f$  = 6 ns)

| Characteristics             | Part Number | Symbol             | Test Condition    | V <sub>EE</sub> (V) | V <sub>CC</sub> (V) | Min | Max | Unit |
|-----------------------------|-------------|--------------------|-------------------|---------------------|---------------------|-----|-----|------|
| Phase difference between    |             | Φι/Ο               | _                 | GND                 | 4.5                 | _   | 17  | ns   |
| input to output             |             |                    |                   | GND                 | 5.0                 | _   | 15  |      |
|                             |             |                    |                   | -4.5                | 4.5                 | _   | _   |      |
| Output enable time          | 74HCT4051D  | $t_{PZL}, t_{PZH}$ | $R_L = 1 k\Omega$ | GND                 | 4.5                 | _   | 62  | ns   |
|                             |             |                    | Figure 1          | GND                 | 5.0                 | _   | 47  |      |
|                             |             |                    |                   | -4.5                | 4.5                 | _   | 45  |      |
|                             | 74HCT4052D  |                    | $R_L = 1 k\Omega$ | GND                 | 4.5                 | _   | 62  | ns   |
|                             |             |                    | Figure 1          | GND                 | 5.0                 | _   | 47  |      |
|                             |             |                    |                   | -4.5                | 4.5                 | _   | 45  |      |
| Output disable time         | 74HCT4051D  | $t_{PLZ}, t_{PHZ}$ | $R_L = 1 k\Omega$ | GND                 | 4.5                 | _   | 42  | ns   |
|                             |             |                    | Figure 1          | GND                 | 5.0                 | _   | 38  |      |
|                             |             |                    |                   | -4.5                | 4.5                 | _   | 38  |      |
|                             | 74HCT4052D  |                    | $R_L = 1 k\Omega$ | GND                 | 4.5                 | _   | 42  | ns   |
|                             |             |                    | Figure 1          | GND                 | 5.0                 | _   | 38  |      |
|                             |             |                    |                   | -4.5                | 4.5                 | _   | 38  |      |
| Control input capacitance   |             | C <sub>IN</sub>    | _                 | _                   | _                   | _   | 10  | pF   |
| Common terminal             | 74HCT4051D  | C <sub>IS</sub>    | Figure 2          | -5.0                | 5.0                 | _   | 70  | pF   |
| capacitance                 | 74HCT4052D  |                    |                   |                     |                     | _   | 40  |      |
| Switch terminal capacitance | 74HCT4051D  | Cos                | Figure 2          | -5.0                | 5.0                 | _   | 15  | pF   |
|                             | 74HCT4052D  |                    |                   |                     |                     | _   | 15  |      |
| Feedthrough capacitance     | 74HCT4051D  | C <sub>IOS</sub>   | Figure 2          | -5.0                | 5.0                 | _   | 2   | pF   |
|                             | 74HCT4052D  |                    |                   |                     |                     | _   | 2   |      |

Note: Operating Range spec of  $T_{opr}$  = -40 °C to 125 °C is applicable only for the products which manufactured after July 2020.



# 12.7. Analog Switch Characteristics (T<sub>a</sub> = 25 °C) (Note)

| Characteristics                            | Part Number | Symbol                | Test Condition                                                                                                             |                         | V <sub>EE</sub> (V) | V <sub>CC</sub> (V) | Тур.  | Unit |
|--------------------------------------------|-------------|-----------------------|----------------------------------------------------------------------------------------------------------------------------|-------------------------|---------------------|---------------------|-------|------|
| Sine Wave Distortion                       |             | THD                   | $R_L = 10 \text{ k}\Omega, C_L = 50 \text{ pF}$                                                                            | $V_{IN} = 8.0 V_{p-p}$  | -4.5                | 4.5                 | 0.020 | %    |
|                                            |             |                       | f <sub>IN</sub> = 1 kHz                                                                                                    | $V_{IN} = 11.0 V_{p-p}$ | -5.5                | 5.5                 | 0.019 |      |
| Maximum frequency                          |             | f <sub>MAX(I/O)</sub> | Adjust f <sub>IN</sub> voltage to obtain                                                                                   | (Note 1)                | -4.5                | 4.5                 | 190   | MHz  |
| response                                   | 74HCT4051D  |                       | 0 dBm at V <sub>OS</sub><br>Increase f <sub>IN</sub> frequency until                                                       | (Note 2)                |                     |                     | 70    |      |
|                                            | 74HCT4052D  |                       | dB meter reads -3 dB<br>$R_L = 50 \Omega$ , $C_L = 10 pF$                                                                  |                         |                     |                     | 110   |      |
|                                            |             |                       |                                                                                                                            | (Note 1)                | -5.5                | 5.5                 | 200   |      |
|                                            | 74HCT4051D  |                       | f <sub>IN</sub> = 1 MHz, sine wave<br>Figure 3                                                                             | (Note 2)                |                     |                     | 80    |      |
|                                            | 74HCT4052D  |                       | 3                                                                                                                          |                         |                     |                     | 135   |      |
| Feed through attenuation (switch OFF)      |             | FTH                   | V <sub>IN</sub> is centered at (V <sub>CC</sub> /2).<br>Adjust input for 0 dBm.                                            |                         | -4.5                | 4.5                 | -50   | dB   |
|                                            |             |                       | $R_L = 600 \Omega$ , $C_L = 50 pF$ ,<br>$f_{IN} = 1 MHz$ , sine wave<br>Figure 4                                           |                         | -5.5                | 5.5                 | -50   |      |
| Crosstalk (control input to signal output) |             | X <sub>talk</sub>     | $R_L = 600 \Omega, C_L = 50 pF,$<br>$f_{IN} = 1 MHz,$                                                                      |                         | -4.5                | 4.5                 | 140   | mV   |
|                                            |             |                       | square wave $(t_r = t_f = 6 \text{ ns})$<br>Figure 5                                                                       |                         | -5.5                | 5.5                 | 180   |      |
| Crosstalk (between any switches)           |             | X <sub>talk</sub>     | Adjust $V_{IN}$ to obtain 0 dBm at input.<br>$R_{I} = 600 \Omega$ , $C_{I} = 50 pF$ ,                                      |                         | -4.5                | 4.5                 | -50   | dB   |
|                                            |             |                       | f <sub>IN</sub> = 1 MHz, sine wave<br>Figure 6                                                                             |                         | -5.5                | 5.5                 | -50   |      |
|                                            |             |                       | $R_L$ = 50 $\Omega$ , $C_L$ = 15 pF,<br>$f_{\text{IN}}$ = 100 KHz,<br>$V_{\text{SWITCH}}$ = 1 $V_{\text{RMS}}$<br>Figure 6 |                         | -4.5                | 4.5                 | -90   | dB   |

Note: These characteristics are determined by design of devices.

Note 1: Input COMMON terminal, and measured at SWITCH terminal.

Note 2: Input SWITCH terminal, and measured at COMMON terminal.



#### 13. AC Test Circuit

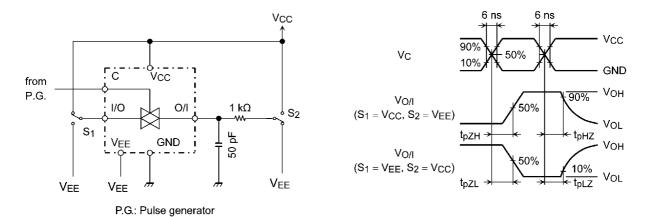


Figure 1 tpLZ, tpHZ, tpZL, tpZH

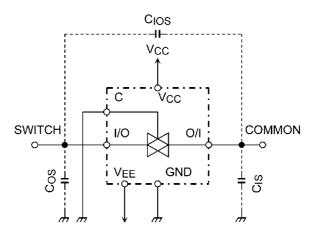


Figure 2 C<sub>IOS</sub>, C<sub>IS</sub>, C<sub>OS</sub>

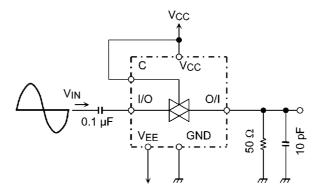


Figure 3 Frequency Response

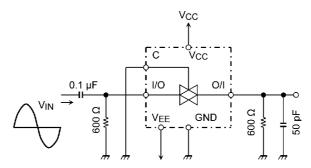
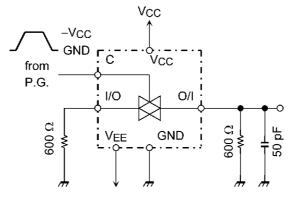


Figure 4 Feedthrough Attenuation





P.G.: Pulse generator

Figure 5 Cross Talk (control input to output signal)

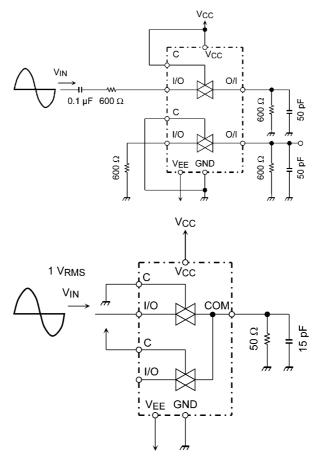
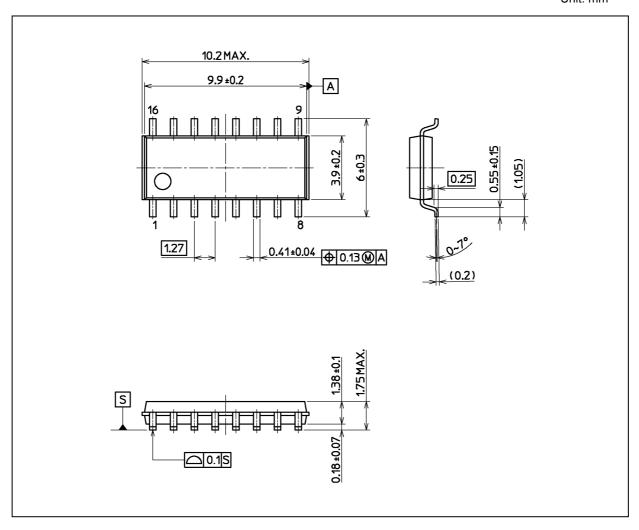


Figure 6 Cross Talk (between any two switches)



# **Package Dimensions**

Unit: mm



Weight: 0.15 g (typ.)

|                  | Package Name(s) |
|------------------|-----------------|
| Nickname: SOIC16 |                 |



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